ELECTRONICS, INC.
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NTE1820
Integrated Circuit
Module, Dual AF PO, 30W/Ch, Dual Power Supply

Features:

- Contains Emitter Follower Circuit for Upgrading
- Case Temperature +125°C is Guaranteed, Thereby Enabling Great Reduction of Heat Sink
- By Attaching Muting Circuit Externally, Pop Noise at Power ON/OFF can be Rejected

Absolute Maximum Ratings: (T_A = +25°C unless otherwise specified)

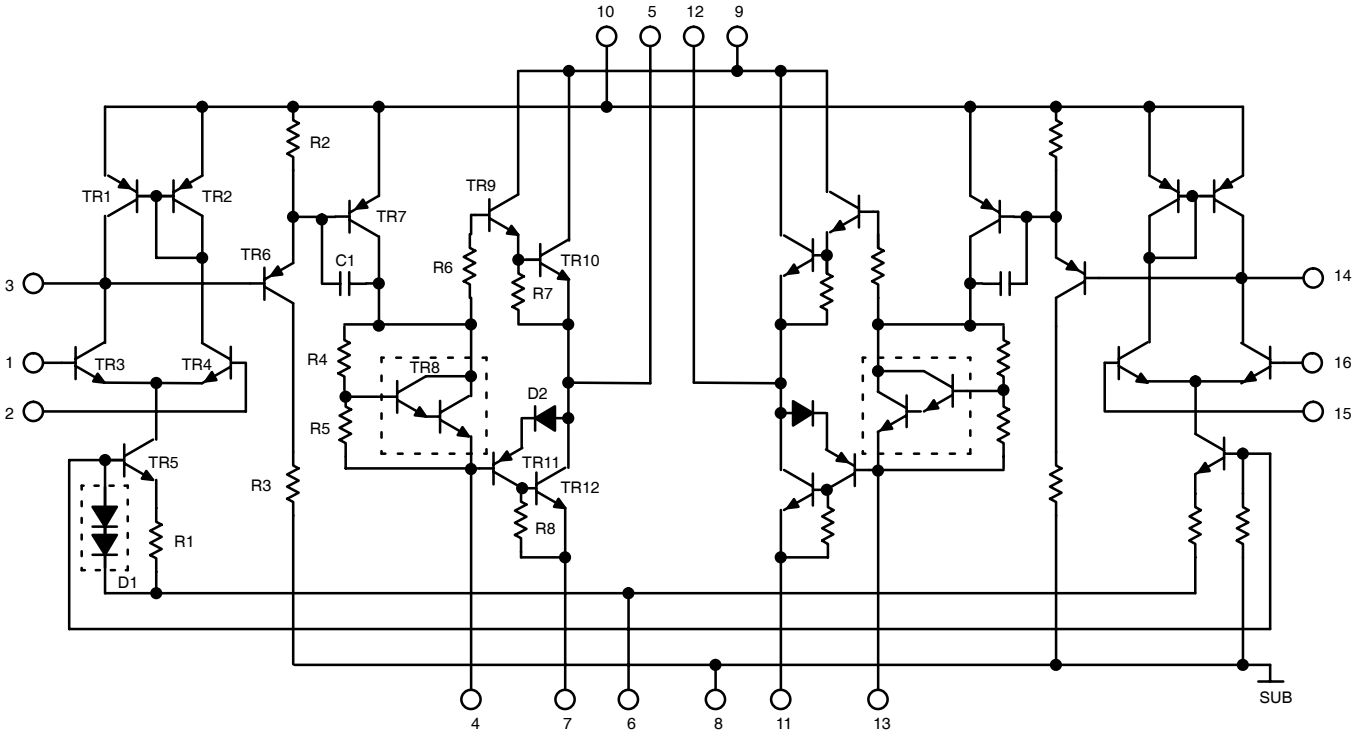
Maximum Supply Voltage, V_{CC}max . . . . . ±43V
Thermal Resistance, Junction−to−Case, R_{thJC} . . . . . 2.2°C/W
Maximum Junction Temperature, T_J . . . . . +150°C
Operating Case Temperature, T_C . . . . . +125°C
Storage Temperature Range, T_{stg} . . . . . −30° to +125°C
Available Time for Load Shorted (V_{CC} = ±27.5V, R_L = 8Ω, P_O = 30W, f = 50Hz), t_s 2sec

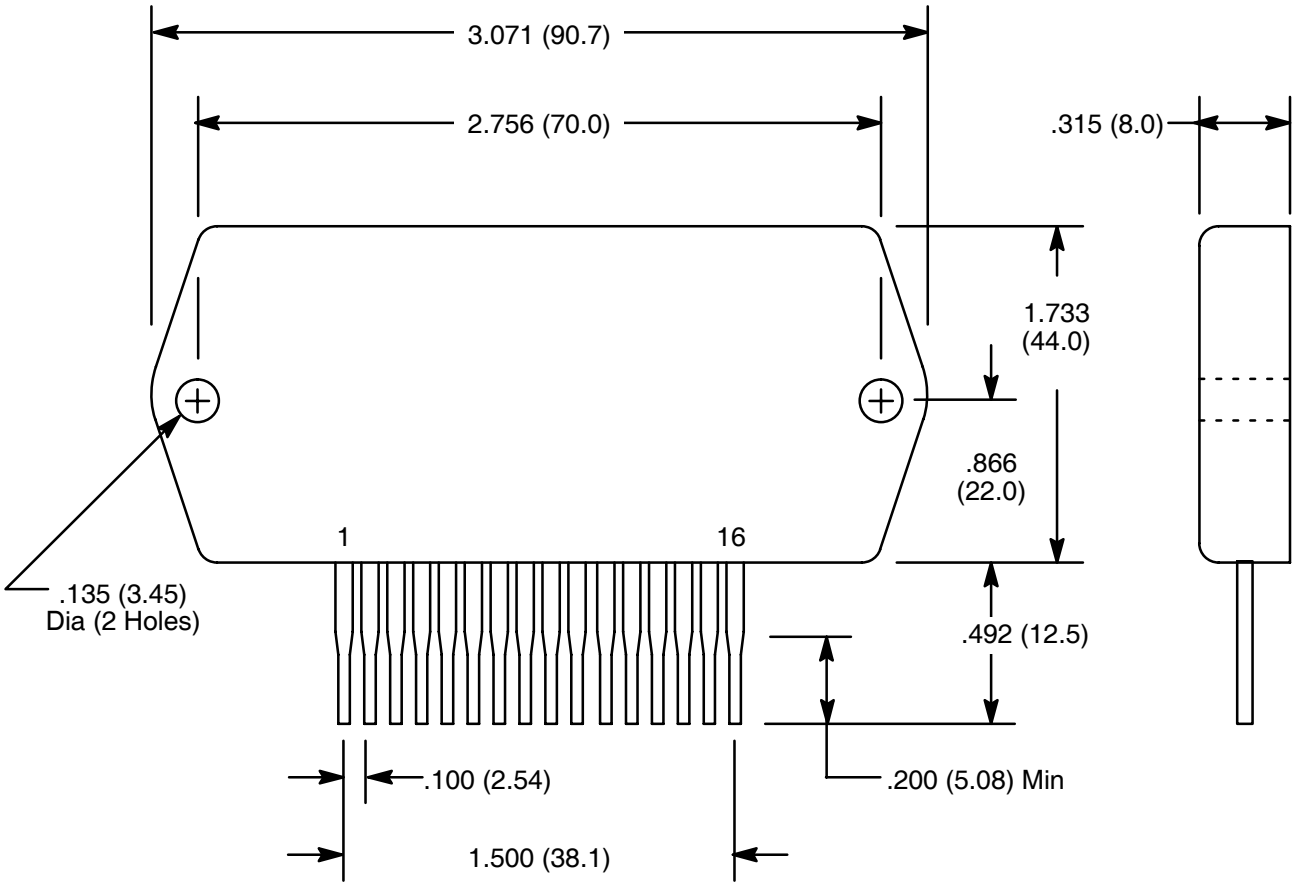
Recommended Operating Conditions: (T_A = +25°C unless othrwise specified)

Recommended Supply Voltage, V_{CC} . . . . . ±27.5V
Load Resistance, R_L 8Ω

Operating Characteristics: (T_A = +25°C, V_{CC} = ±27.5V, R_L = 8Ω, R_g = 600Ω, VG = 40dB unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Quiescent Current	I_{CCO}	V_{CC} = ±34V	35	70	120	mA
Output Power	$P_{O(1)}$	THD = 0.02%, f = 20Hz to 20kHz	30	–	–	W
	$P_{O(2)}$	V_{CC} = ±23V, THD = 0.08%, R_L = 4Ω, f = 1kHz	30	–	–	W
Total Harmonic Distortion	THD	P_O = 1W, f = 20Hz to 20kHz	–	–	0.02	%
Frequency Response	f_L, f_H	P_O = 1W	10 to 100k		–	Hz
Input Resistance	r_i	P_O = 1W	–	90k	–	Ω
Output Noise Voltage	V_{NO}	V_{CC} = ±34V	–	–	1.2	mV_{rms}
Midpoint Voltage	V_N	V_{CC} = ±34V	−70	–	+70	mV


10
5
12
9
R2
TR1
TR2
TR9
TR7
TR6
C1
R6
TR10
R7
3
14
1
TR3
TR4
R4
TR8
16
2
D2
15
R5
TR5
TR11
R3
TR12
R8
R1
D1
SUB
4
7
6
8
11
13


3.071 (90.7)
2.756 (70.0)
.315 (8.0)
1.733
(44.0)
.866
(22.0)
1
16
.135 (3.45)
Dia (2 Holes)
.492 (12.5)
.100 (2.54)
.200 (5.08) Min
1.500 (38.1)